

نظم القياس الإلكترونية

Electronic Measurement Systems

(EMS)

كلية الهندسة الكهربائية والالكترونية - جامعة حلب
د. أسعد كعدان

المحاضرتين 5-6 – أخطاء القياس والضجيج

مصادر المحاضرة

- Electronic Instrumentation, Prof. Dr. Kofi Makinwa
<https://ocw.tudelft.nl/courses/electronic-instrumentation/>
 - Lecture 3 – Errors and Noise

Two kinds of errors (uncertainty):

- a. Deterministic errors
 - e.g. source loading, offset, gain error
- b. Random (stochastic) errors
 - e.g. thermal noise

Assuming that the output of a system $z = f(a, b, c, \dots)$

Then the total error due to deterministic parameter uncertainty is:

$$\Delta z = \left| \frac{\partial f(a, b, c, \dots)}{\partial a} \right| \Delta a + \left| \frac{\partial f(a, b, c, \dots)}{\partial b} \right| \Delta b + \left| \frac{\partial f(a, b, c, \dots)}{\partial c} \right| \Delta c + \dots$$

where Δz denotes the uncertainty in z due to parameter a , which is specified with uncertainty Δa etc..

The derivatives above are called sensitivities.

Example: Combining additive errors:

For $z = a + b$ or $z = a - b$ with Δa the uncertainty in a and Δb the uncertainty in b , the overall uncertainty follows as:

$$\Delta z = \left| \frac{\partial(a \pm b)}{\partial a} \right| \Delta a + \left| \frac{\partial(a \pm b)}{\partial b} \right| \Delta b = \Delta a + \Delta b$$

By extension, the effect of deterministic errors (e.g. offset, gain error etc.) in a linear time-invariant (LTI) system can be determined by superposition.

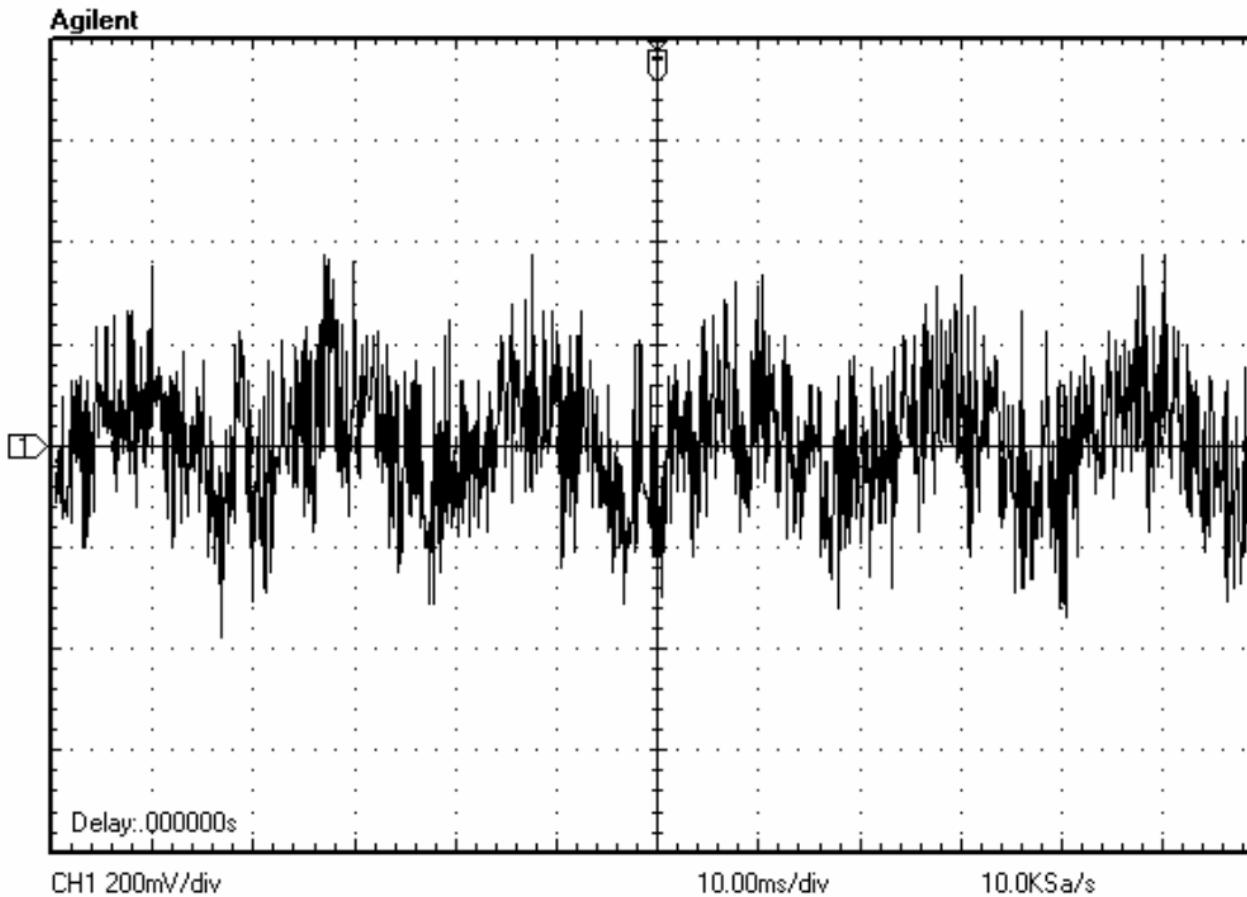
- *Interference* is caused by *external* signals e.g. 50 Hz hum
- *Noise* is caused by stochastic processes in the measurement system itself e.g. thermal noise.

- Noise and interference are usually additive error signals
⇒ they can both be modeled by extra error sources to the system

- Note that interference and noise should not be confused with signal *distortion*, which is caused non-linearities in either the amplitude or the frequency domain.

Noise + 50 Hz interference

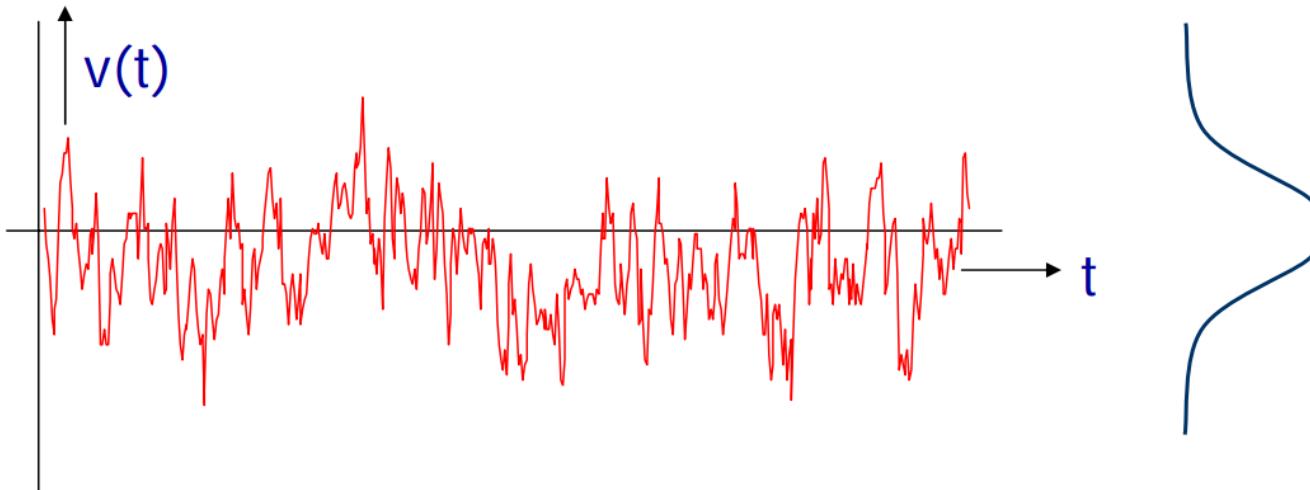
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- ALL resistors exhibit thermal noise
- Thermal noise has a uniform (white) frequency spectrum
- noise power density: $P_n = 4kT$ (W/Hz)
 - where k is Boltzmann's constant and T is absolute temperature
- At room temperature (293 K): $P_n = 4kT = 1.62 \times 10^{-20}$ (W/Hz)
- For a resistor: $P = V_{rms}^2/R = I_{rms}^2R$
- => noise voltage with spectral density: $v_n = \sqrt{4kTR}$ (V/Hz^{1/2})
- => noise current with spectral density: $i_n = \sqrt{4kT/R}$ (A/Hz^{1/2})

Thermal noise (1)

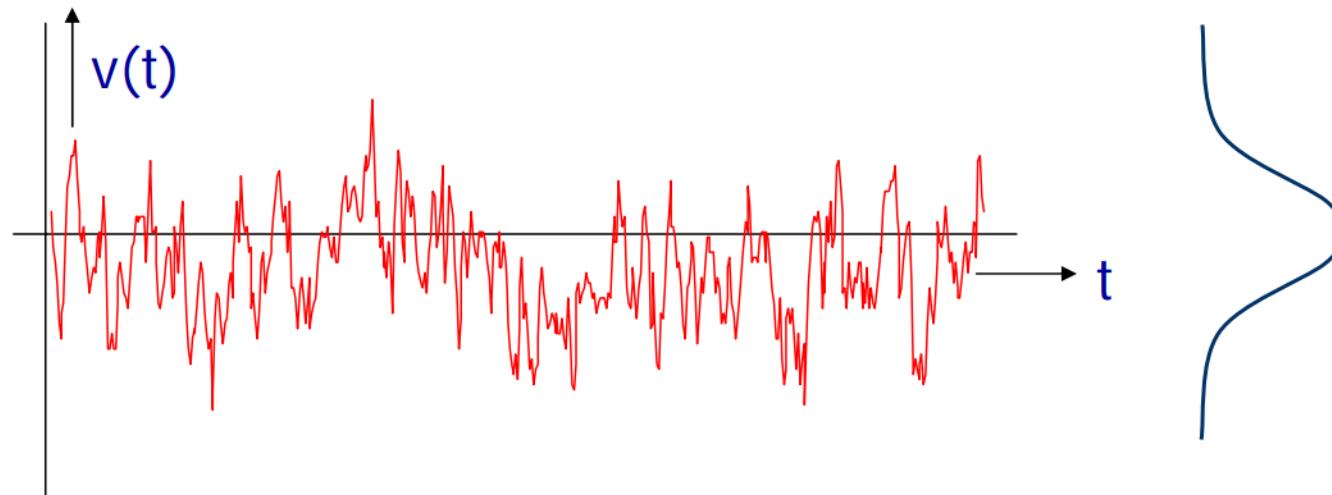
- (Thermal) noise is stochastic, i.e. its amplitude at a given time t cannot be predicted
- Thermal noise has a Gaussian amplitude distribution



$$p(V)dV = \frac{1}{V_n \sqrt{2\pi}} e^{-\left(\frac{V^2}{2V_n^2}\right)} dV$$

Thermal noise (2)

- In the presence of thermal noise, the detection limit is usually specified as the standard deviation (or sigma) V_n
- A good estimate of its peak value (e.g. as seen on a wide-band scope) is 5-sigma



$$p(V)dV = \frac{1}{V_n \sqrt{2\pi}} e^{-\left(\frac{V^2}{2V_n^2}\right)} dV$$

Shot noise

- Shot noise is the result of the fact that an electrical current is the result of the motion of discrete charge carriers.
- This can be compared with hail on a roof: even if the average current (mass flow) is constant, the amount of charge carriers (ice lumps), measured in different intervals with the same length Δt , will, in general, be different. The relative fluctuation becomes greater as Δt becomes smaller and smaller.
- Like thermal noise, shot noise has a uniform frequency spectrum and so is also a form of white noise.
- If a current I consists of charge carriers with charge q that move independently of each other, then the spectral noise current is given by $i_n = \sqrt{2qI}$ (A/Hz^{1/2}).
- This equation applies to p-n junctions (diodes, transistors, etc.) but not to metallic conductors where there is more long-range correlation between the movement of the charge carriers. In such conductors, the shot noise will thus be smaller!

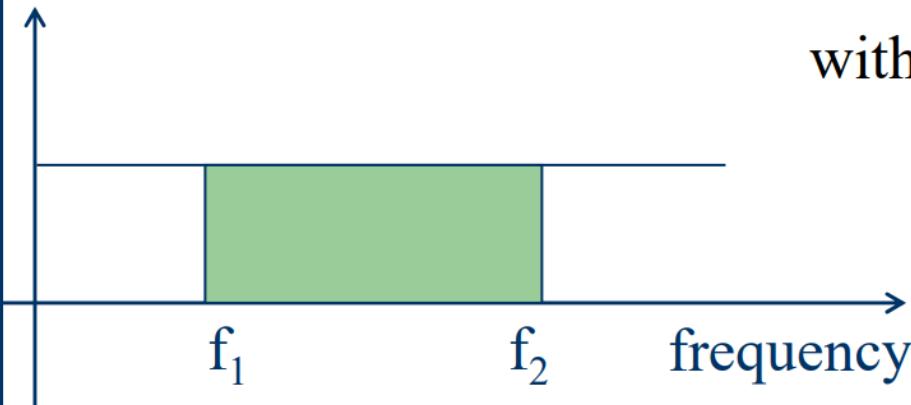
Calculating shot noise

i_n is proportional to the square-root of current!

$$i_n = \sqrt{2qI} \quad (\text{A/Hz}^{1/2})$$

$$I_n(\text{rms}) = i_n \sqrt{B} = \sqrt{2qI_{\text{DC}}B} \quad (\text{A})$$

with bandwidth $B = f_2 - f_1$

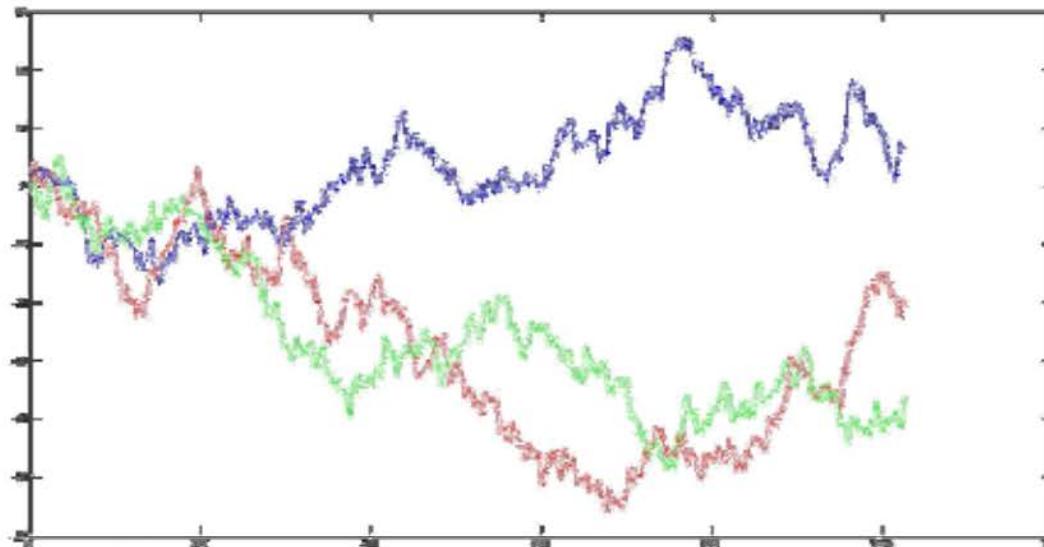


Example (for $B = 10$ Hz):

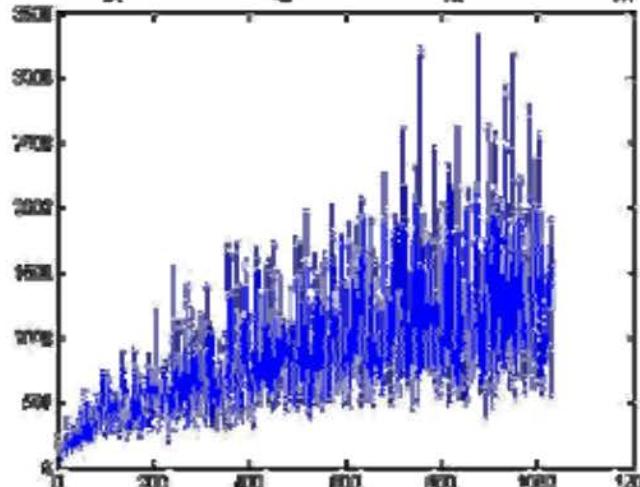
- $I = 1 \text{ A} \Rightarrow \text{noise current } I_n(\text{rms}) = 57 \text{ nA (0.000006%)}$
- $I = 1 \text{ pA} \Rightarrow \text{noise current } I_n(\text{rms}) = 56 \text{ fA (5.6%)}$
- Shot noise is important at low current levels

- Both thermal and shot noise are the result of fundamental physical processes and so form a fundamental detection limit.
- Apart from these types of noise, “real” electronic components also suffer from several sources of “excess noise.”
- Resistors exhibit current-dependent 1/f noise: $V_n(\text{rms}) = c \cdot I$ where the constant c is determined by resistor quality (price).
- Transistors (especially MOSFETs) exhibit area-dependent 1/f noise: where $V_n(\text{rms}) \propto 1/\sqrt{\text{Area}}$
- 1/f noise has a 1/f POWER spectrum, i.e. the spectral noise power per decade (or per octave) is constant.
- 1/f noise is sometimes referred to as “pink” or “flicker” noise

1/f noise example



3 instances
of 1/f noise

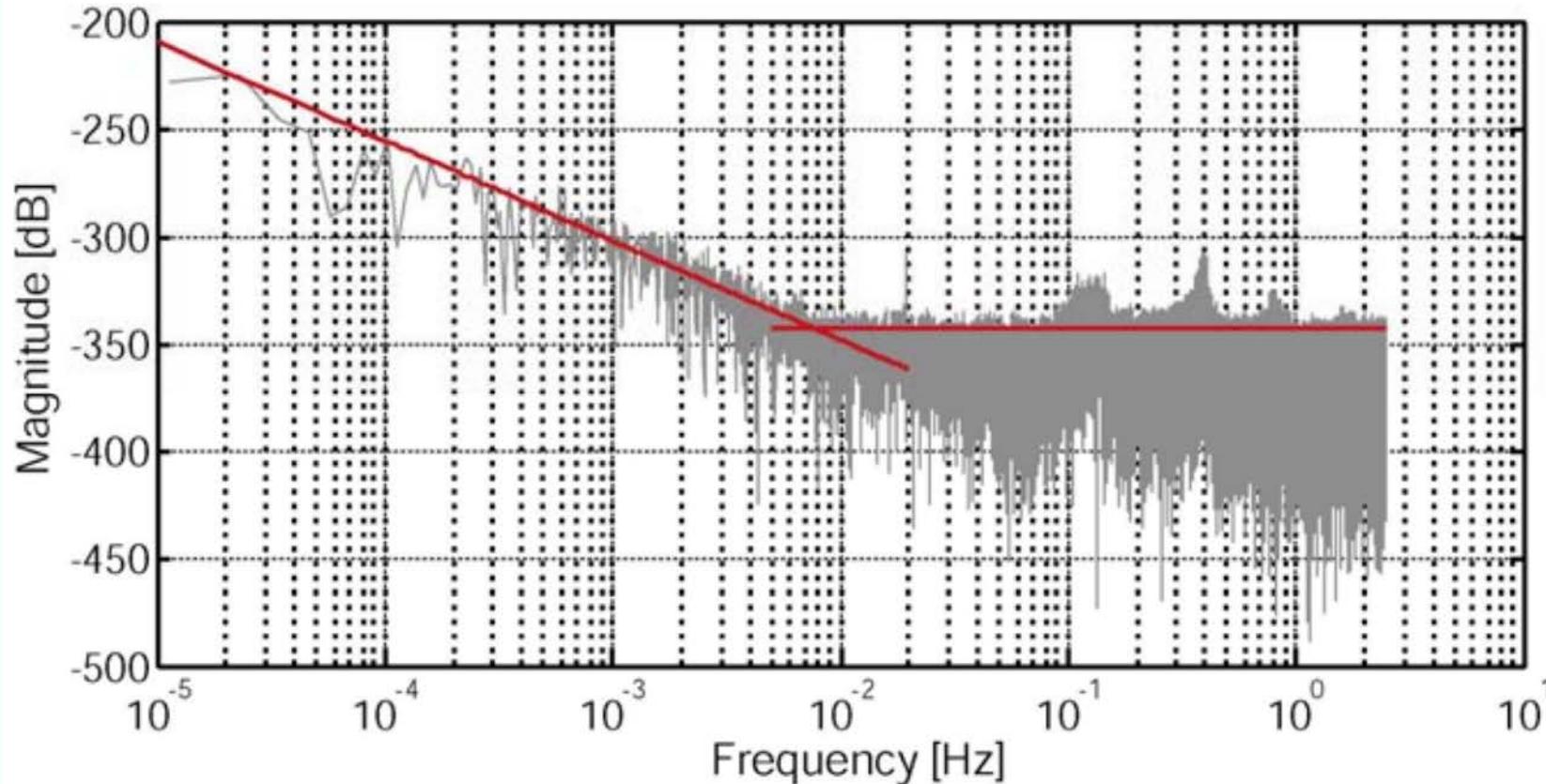


Peak amplitude increases for as measurement time increases?!

$$x \sim t$$

More and more important for long (low-frequency) measurements!

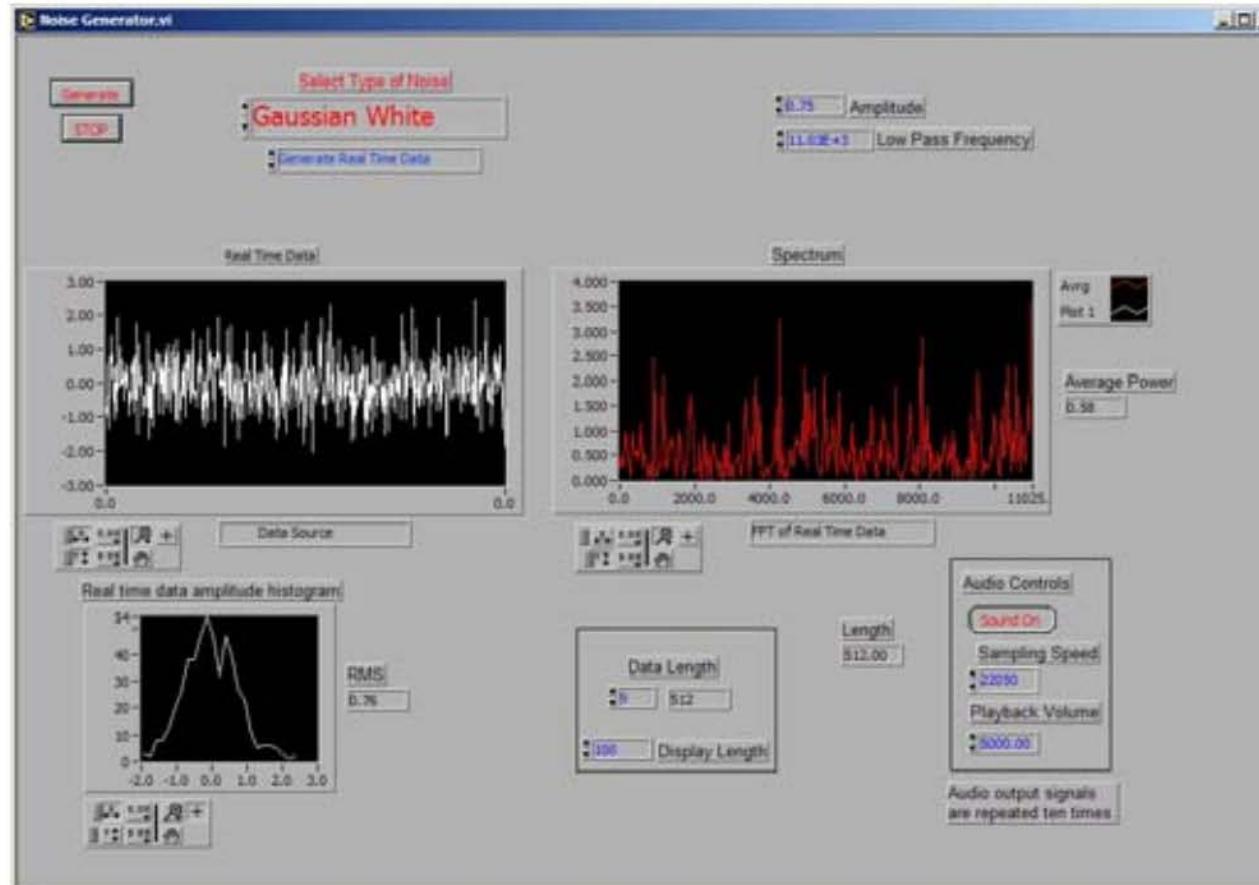
Spectrum of a critically damped micro-mechanical structure



Two spectral regimes:
a. $1/f$ noise and
b. frequency independent white noise.

On-line noise demo

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<http://socrates.berkeley.edu/~phylabs/bsc/Supplementary/NoiseGenerator.html>

- Noise is also present in non-electrical domains
- Thermal noise \Rightarrow some kind of energy dissipation

- In the mechanical domain this is due to damping
- In very small structures (MEMS), Brownian noise is also important
- In the thermal domain this is due to thermal resistance

- Shot noise \Rightarrow small amount of energy-carrying particles
- In the optical domain, photon shot noise is significant

Errors (uncertainties) due to:

- a. Noise,
- b. Electro-Magnetic Interference (EMI)

are referred to as **Stochastic (random) sources of error (uncertainty)**.

The effect of stochastic error(s) on overall system specifications can be evaluated using Gauss law of error propagation:

$$\underline{z} = f(\underline{a}, \underline{b}, \underline{c}, \dots)$$

$$\sigma_z^2 = \left(\frac{\partial f(a, b, c, \dots)}{\partial a} \right)_{\underline{a}, \underline{b}, \underline{c}, \dots}^2 \cdot \sigma_a^2 + \left(\frac{\partial f(a, b, c, \dots)}{\partial b} \right)_{\underline{a}, \underline{b}, \underline{c}, \dots}^2 \cdot \sigma_b^2 + \left(\frac{\partial f(a, b, c, \dots)}{\partial c} \right)_{\underline{a}, \underline{b}, \underline{c}, \dots}^2 \cdot \sigma_c^2 + \dots$$

where σ_z^2 denotes the variance (uncertainty) in parameter z with average value \underline{z} due to parameter a , which is specified with uncertainty σ_a etc..

Combining additive errors:

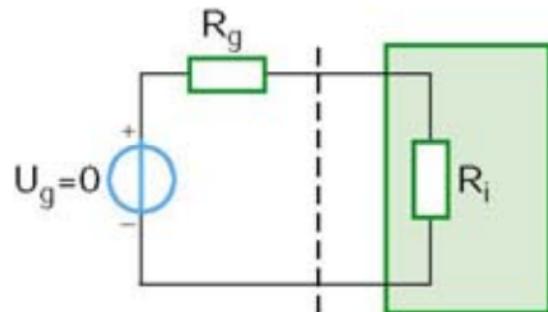
For $z = a + b$ or $z = a - b$ the overall uncertainty follows as:

$$\underline{z} = \underline{a} \pm \underline{b}$$

$$\sigma_z^2 = \left(\frac{\partial(a \pm b)}{\partial a} \right)_{\underline{a}, \underline{b}, \underline{c}, \dots}^2 \cdot \sigma_a^2 + \left(\frac{\partial(a \pm b)}{\partial b} \right)_{\underline{a}, \underline{b}, \underline{c}, \dots}^2 \cdot \sigma_b^2 = \sigma_a^2 + \sigma_b^2$$

Hence, the **variances** of stochastic errors in a linear system can be linearly added.

In case of distributed noise voltages or currents:



Combining additive errors:

For $z = a + b$ or $z = a - b$, the overall uncertainty follows as:

$$\underline{z} = \underline{a} \pm \underline{b}$$

$$\sigma_z^2 = \left(\frac{\partial(\underline{a} \pm \underline{b})}{\partial \underline{a}} \right)_{\underline{a}, \underline{b}, \underline{c}, \dots}^2 \cdot \sigma_a^2 + \left(\frac{\partial(\underline{a} \pm \underline{b})}{\partial \underline{b}} \right)_{\underline{a}, \underline{b}, \underline{c}, \dots}^2 \cdot \sigma_b^2 = \sigma_a^2 + \sigma_b^2$$

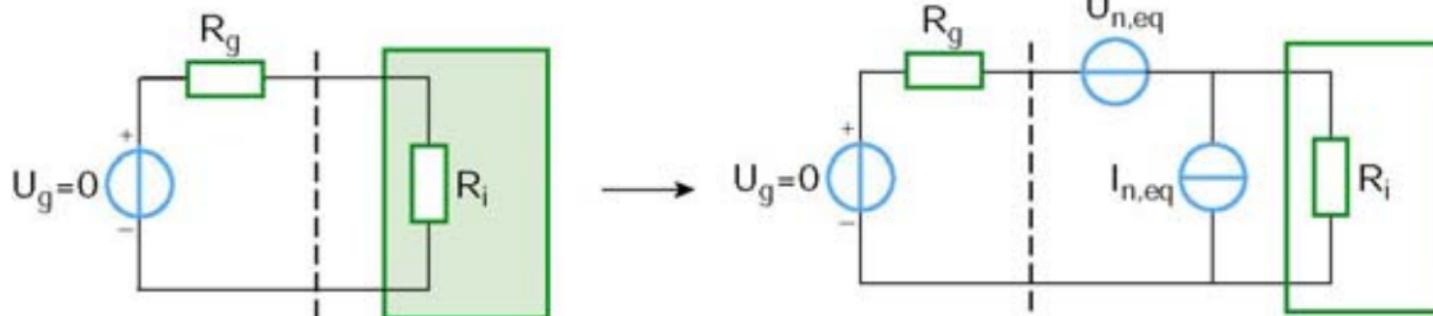
Hence, the **variances** of stochastic errors in a linear system can be linearly added.

In case of distributed noise voltages or currents:

$$u_{n,eq} = \sqrt{u_{n1}^2 + u_{n2}^2}$$

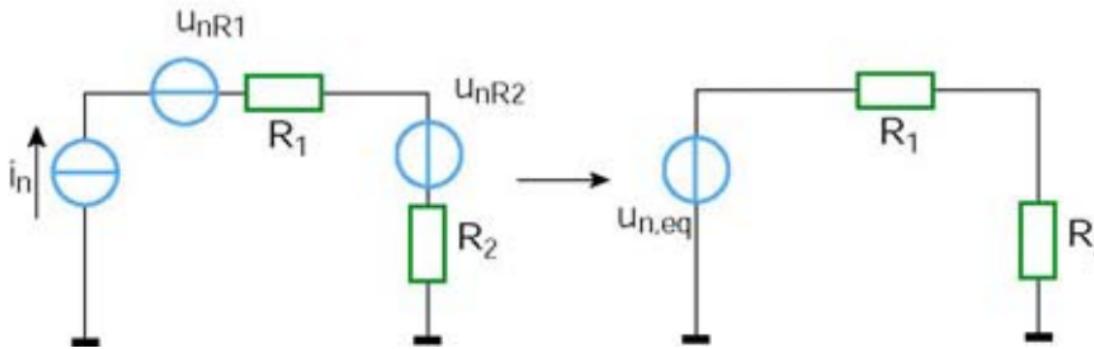
$$i_{n,eq} = \sqrt{i_{n1}^2 + i_{n2}^2}$$

Provided these are independent !



Noise paradox:

What is the equivalent noise voltage in a circuit with two resistors connected to a noise current source ?



Adding the thermal noise powers of R_1 and R_2 to the noise power due to i_n flowing through R_1 and i_n flowing through R_2 :

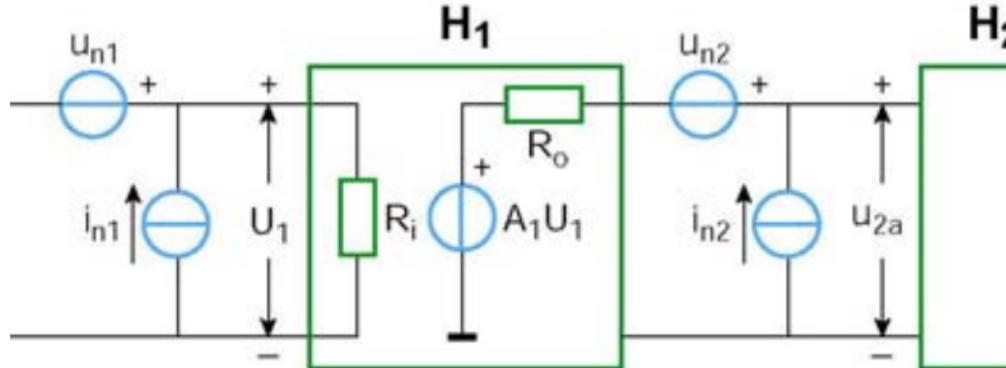
$$(a) \overline{u_{n1,eq}^2} = \overline{u_{n,R1}^2} + \overline{u_{n,R2}^2} + \overline{i_n^2} R_1^2 + \overline{i_n^2} R_2^2 = \\ X \quad \overline{u_{n,R1}^2} + \overline{u_{n,R2}^2} + \overline{i_n^2} (R_1^2 + R_2^2)$$

Adding the thermal noise powers of R_1 and R_2 to the noise power due to i_n flowing through R_1 plus R_2 :

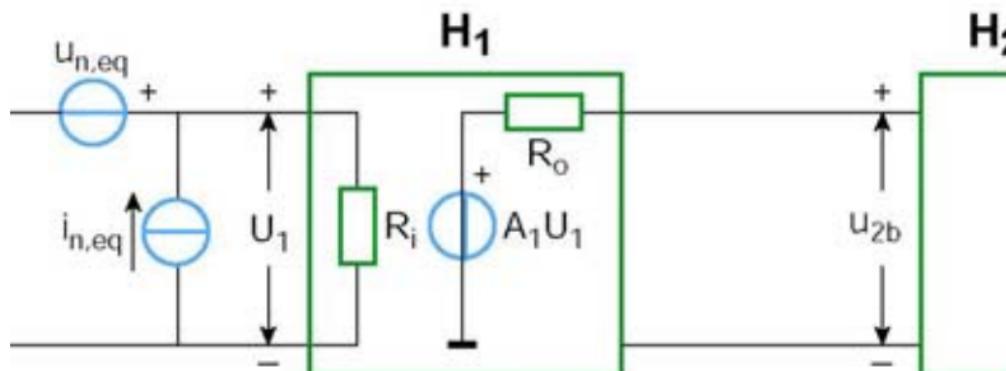
$$V \quad (b) \overline{u_{n2,eq}^2} = \overline{u_{n,R1}^2} + \overline{u_{n,R2}^2} + \overline{i_n^2} (R_1 + R_2)^2$$

Equivalent input sources

General approach for finding equivalent input noise sources:



Note: equivalent noise is independent of source impedance!



Extreme case 1:
open input.

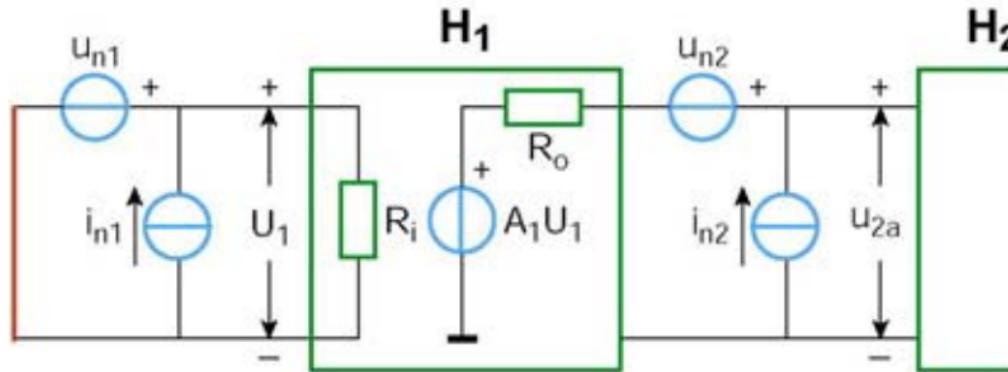
$$\left. \begin{aligned} u_{2a}^2 &= (i_{n1} R_i A_1)^2 + (i_{n2} R_o)^2 + u_{n2}^2 \\ u_{2b}^2 &= (i_{n,eq} R_i A_1)^2 \\ u_{2a}^2 &= u_{2b}^2 \end{aligned} \right\}$$

Hence:

$$i_{n,eq}^2 = i_{n1}^2 + \frac{u_{n2}^2 + i_{n2}^2 R_o^2}{A_1^2 R_i^2}$$

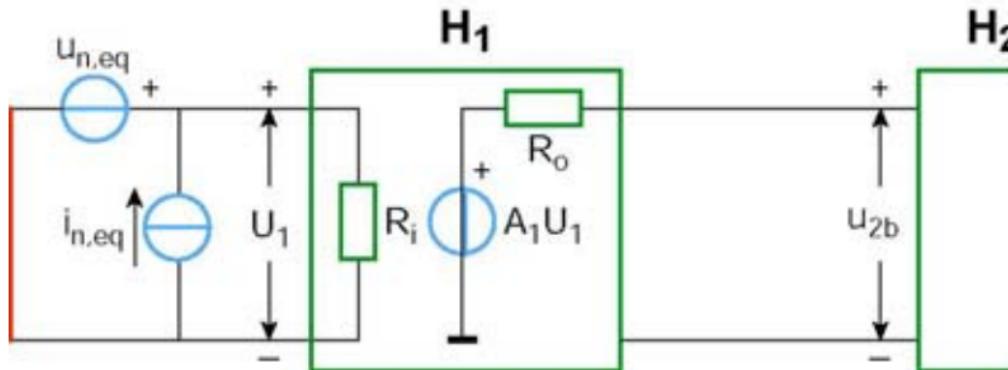
Equivalent input sources

General approach for finding equivalent input noise sources:



Note: equivalent noise is independent of source impedance!

Extreme case 2:
short-circuited input.



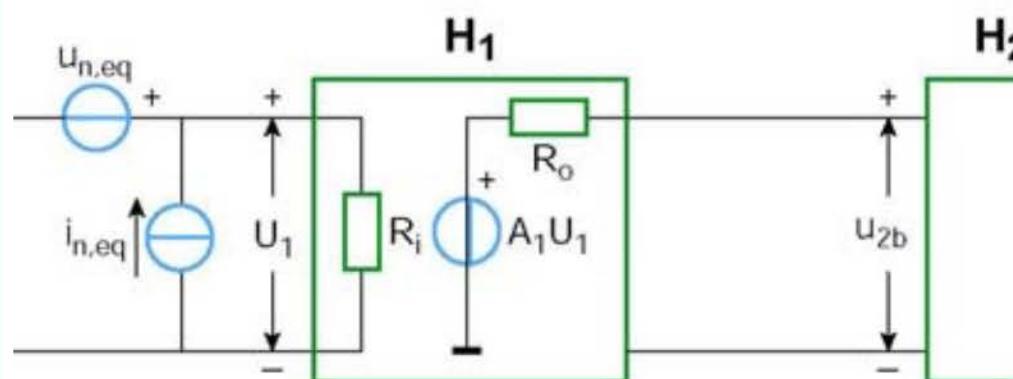
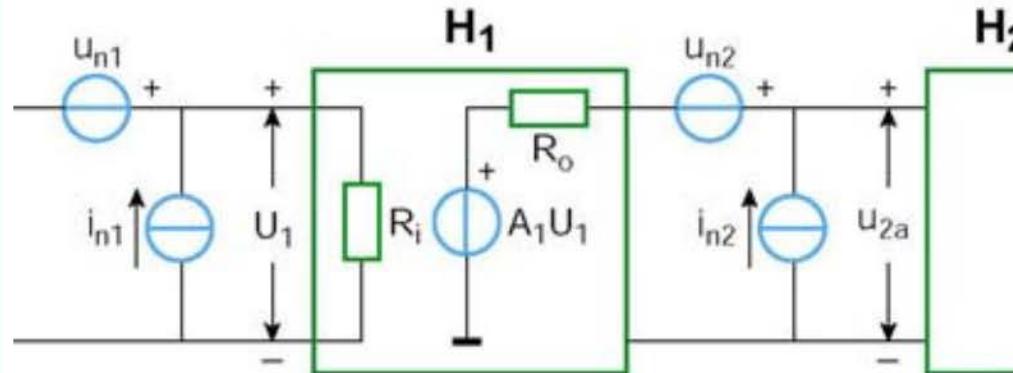
$$\left. \begin{aligned} u_{2a}^2 &= (u_{n1}A_1)^2 + (i_{n2}R_o)^2 + u_{n2}^2 \\ u_{2b}^2 &= (u_{n,eq}A_1)^2 \\ u_{2a}^2 &= u_{2b}^2 \end{aligned} \right\}$$

Hence:

$$u_{n,eq}^2 = u_{n1}^2 + \frac{u_{n2}^2 + i_{n2}^2 R_o^2}{A_1^2}$$

Equivalent input sources

General approach for finding equivalent input noise sources:



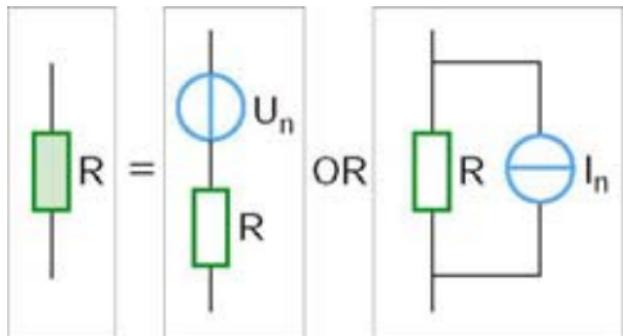
$$u_{n,eq}^2 = u_{n1}^2 + \frac{u_{n2}^2 + i_{n2}^2 R_o^2}{A_1^2}$$

$$i_{n,eq}^2 = i_{n1}^2 + \frac{u_{n2}^2 + i_{n2}^2 R_o^2}{A_1^2 R_i^2}$$

Recommendations for low-noise performance:
Focus design effort on first stage: low noise and high gain, A_1 .

Noise bandwidth

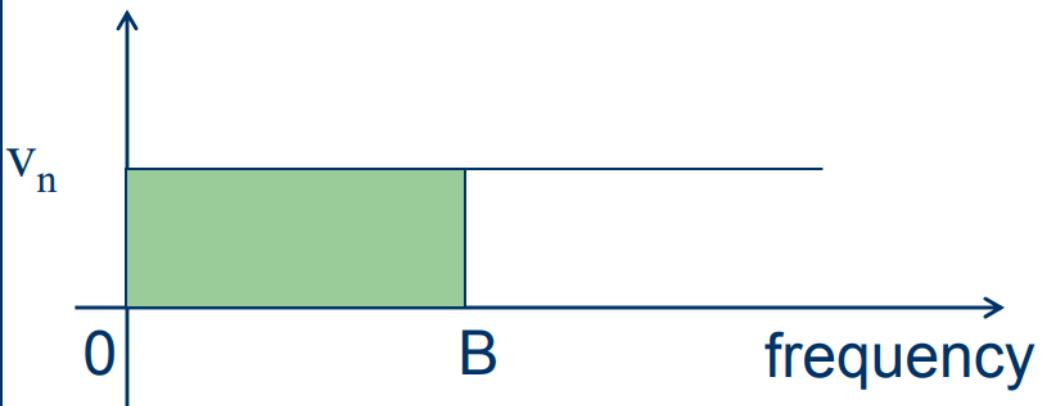
Noise in components is usually specified in terms of the **noise spectral power**, s_n . In case of a resistor:



$$s_{nu,Z} = 4k_B T |Z| = 4k_B T R \text{ [V}^2/\text{Hz]}$$

$$s_{ni,Z} = \frac{4k_B T}{|Z|} = \frac{4k_B T}{R} \quad [\text{A}^2/\text{Hz}]$$

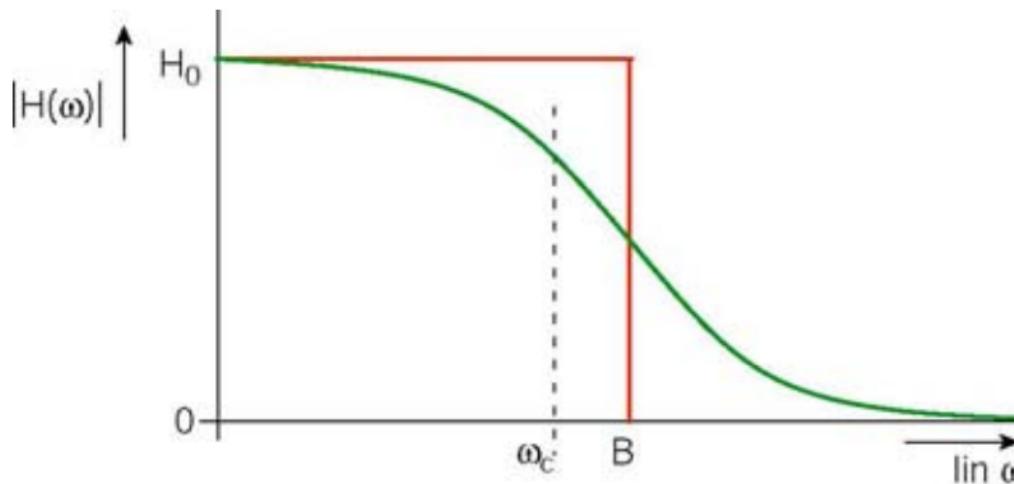
Noise bandwidth is the bandwidth of a theoretical low-pass filter with an abrupt cut-off frequency at B. A practical low-pass filter will have a more gradual transition from pass-band to stop-band, $H(\omega)$.



At 20°C and into a 10kHz bandwidth, a 10kΩ resistor generates 1.3 μVrms.

is defined as the bandwidth of a “brick wall” filter with an abrupt cut-off frequency at B . A practical system is specified by a low-pass filter with a more gradual transition from pass-band to stop-band, $H(\omega)$.

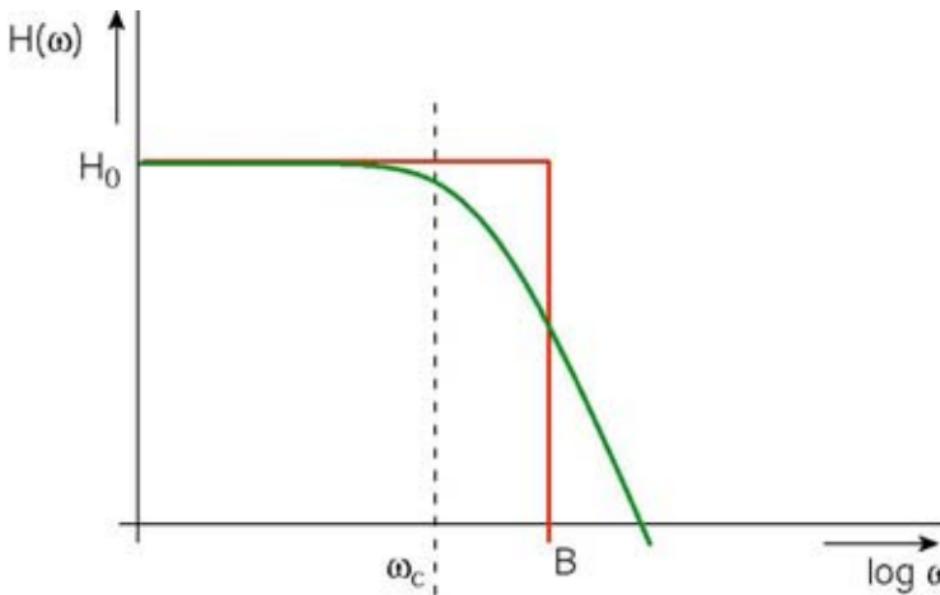
The **Noise bandwidth** B of a practical low-pass filter can be obtained from its transfer function, $H(\omega)$ as follows:



$$P_n = |H_o|^2 B = \int_0^{\infty} |H(\omega)|^2 d\omega \rightarrow B = \frac{1}{|H_o|^2} \int_0^{\infty} |H(\omega)|^2 d\omega$$

Noise bandwidth of a first-order system

$$P_n = |H_o|^2 B = \int_0^{\infty} |H(\omega)|^2 d\omega \rightarrow B = \frac{1}{|H_o|^2} \int_0^{\infty} |H(\omega)|^2 d\omega$$



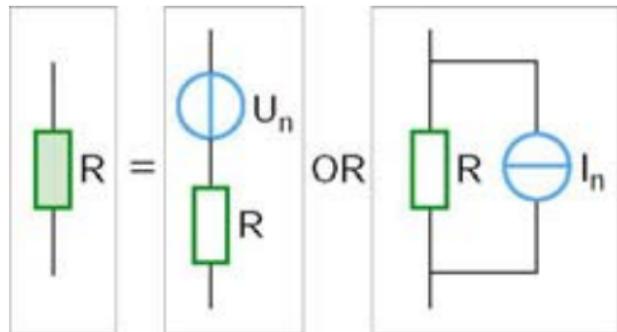
$$\text{For } H_o=1: B = \int_0^{\infty} \frac{d\omega}{1 + (\omega\tau)^2} = \frac{1}{\tau} \arctg(\omega\tau) \Big|_0^{\infty} = \frac{\pi}{2\tau} = \frac{\pi}{2} \omega_c [\text{rad/s}],$$

For noise calculations, a “correction factor” $\pi/2$ is required

Noise in passive components

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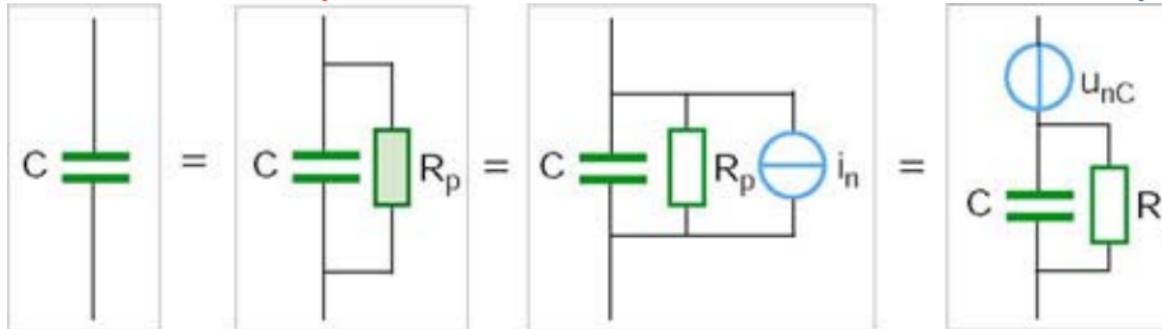
Noise in impedance, Z , is primarily due to the dissipating (resistive) part, R :



$$s_{nu,Z} = 4k_B T |Z| = 4k_B T R \text{ [V}^2/\text{Hz]}$$

$$s_{ni,Z} = \frac{4k_B T}{|Z|} = \frac{4k_B T}{R} \text{ [A}^2/\text{Hz}]$$

Reactive components are not free of noise due to parasitics:



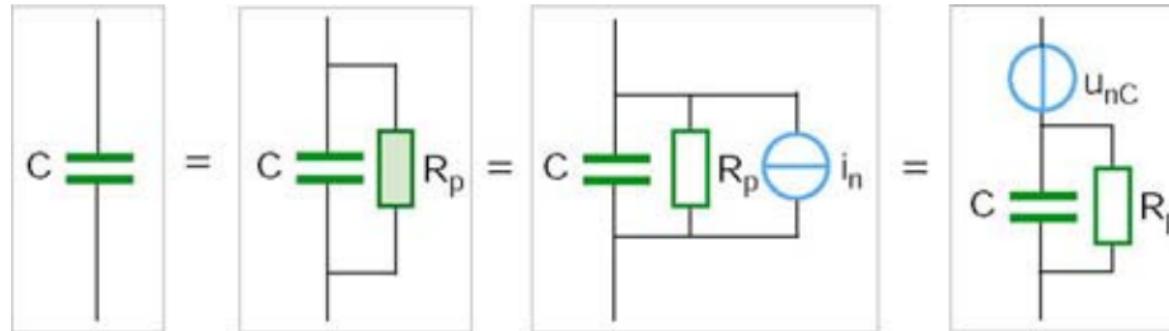
$$\overline{u_{nC}^2} = \int_0^\infty |Z(\omega)|^2 d\omega = i_n^2 \int_0^\infty R_p^2 \frac{d\omega}{1 + (\omega R_p C)^2} = i_n^2 R_p^2 \frac{2\pi}{4R_p C} = \frac{4k_B T}{2\pi R_p} R_p^2 \frac{\pi}{2R_p C} = \frac{k_B T}{C}$$

Noise in passive components

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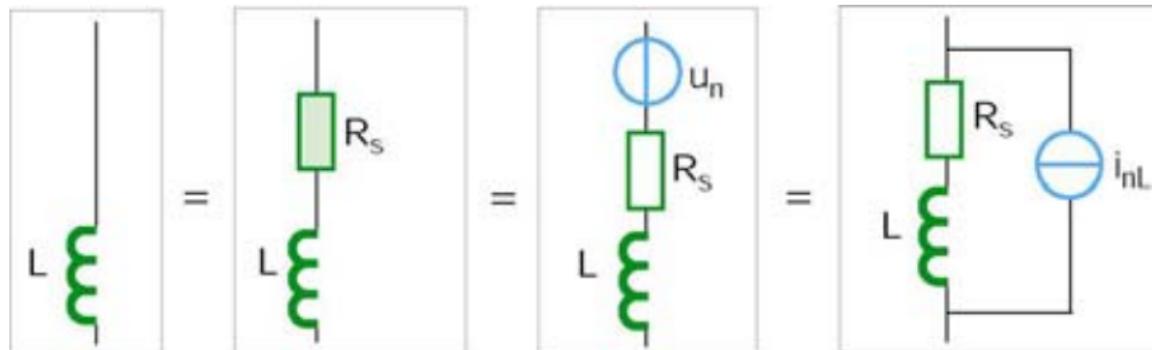
Reactive components are not free of noise due to parasitics:

In a capacitor:



$$\overline{u_{nC}^2} = \int_0^\infty i_n^2 |Z(\omega)|^2 d\omega = i_n^2 \int_0^\infty R_p^2 \frac{d\omega}{1 + (\omega R_p C)^2} = i_n^2 R_p^2 \frac{2\pi}{4R_p C} = \frac{4k_B T}{2\pi R_p} R_p^2 \frac{\pi}{2R_p C} = \frac{k_B T}{C}$$

Similarly,
in an inductor:



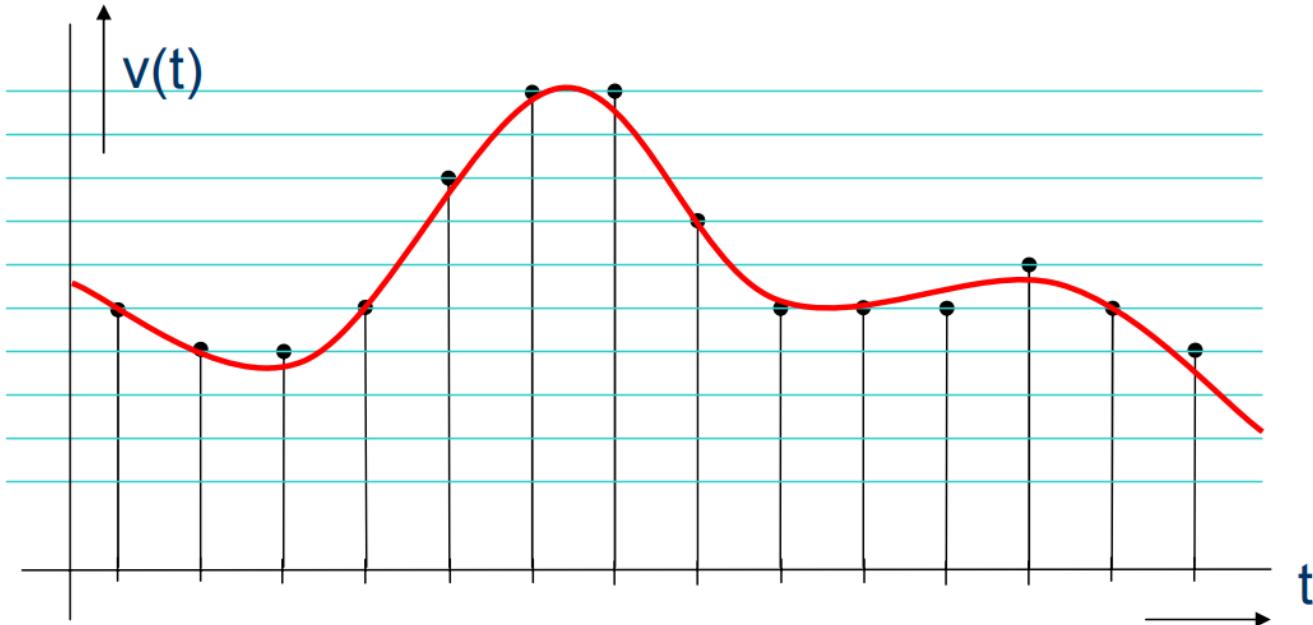
$$\overline{i_{nL}^2} = \int_0^\infty \frac{u_n^2}{|Z(\omega)|^2} d\omega = u_n^2 \int_0^\infty \frac{d\omega}{R_s^2 + (\omega L)^2} = \frac{4k_B T R_s}{2\pi} \times \frac{1}{R_s^2} \int_0^\infty \frac{d\omega}{1 + \left(\frac{\omega L}{R_s}\right)^2} = \frac{k_B T}{L}$$

SNR is defined as the ratio between signal power and noise power expressed in dB:

$$\frac{S}{N} = 10 \log\left(\frac{P_s}{P_n}\right) = 10 \log\left(\frac{V_s(\text{rms})}{V_n(\text{rms})}\right)^2 = 20 \log\left(\frac{V_s(\text{rms})}{V_n(\text{rms})}\right)$$

Notes:

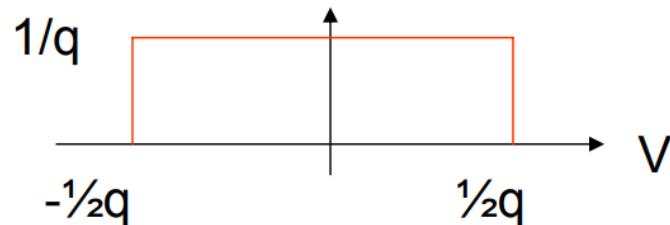
- Since the form of the signal and that of the noise may differ significantly, SNR should not be calculated from signal amplitudes but from rms values.
- A given SNR is always associated with a certain bandwidth.
- For maximum SNR, the bandwidth of a measurement system should be about the same as the expected signal bandwidth



Signal is quantized in both amplitude and in time

- Range: $0 - V_{\text{ref}}$
- Number of bits: n
- Number of levels: 2^n
- “step-size”: $q = V_{\text{ref}} \cdot 2^{-n}$
- error: $-\frac{1}{2}q < V < \frac{1}{2}q$
- For a busy signal (one that jumps between many quantization levels), this error can be modeled as random noise with a uniform pdf
- The associated standard deviation e is then given by:

Probability distr. function $p(V)$



$$e = \sqrt{\frac{1}{q} \int_{-q/2}^{q/2} V^2 dV} = \frac{1}{\sqrt{12}} q$$

Sources of interference

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Interference source

Interference
sensitive system

Coupling mechanism

electrostatic discharge

conduction

integrated circuit

transformer (50 Hz)

magnetic field

audio system

Switched-mode PSU

electric field

high-impedance sensor

HF digital circuit

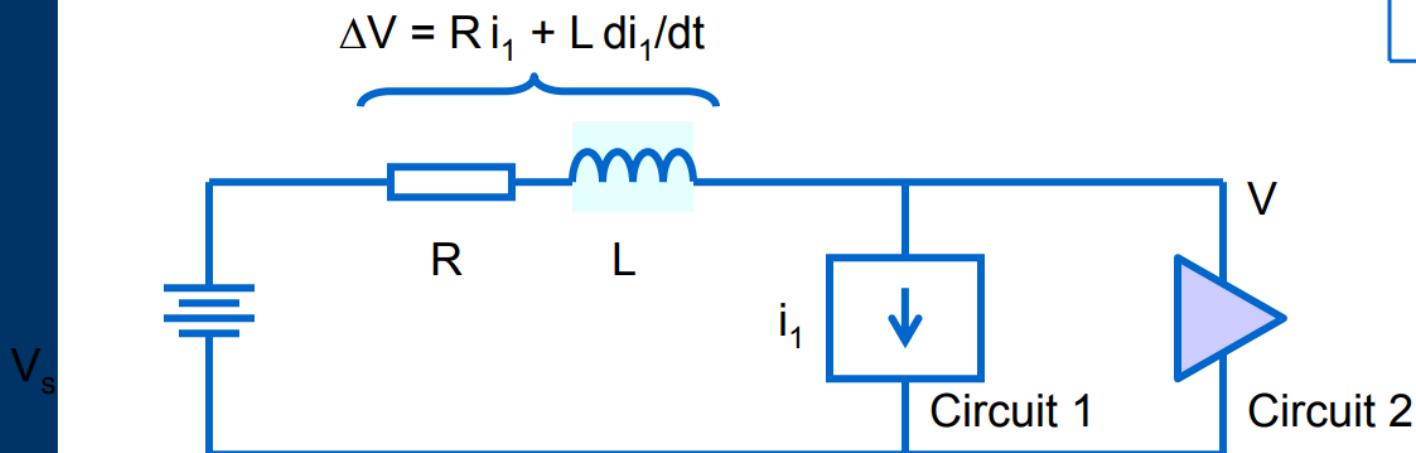
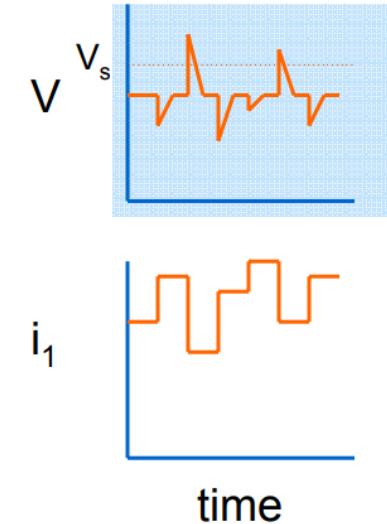
electromagnetic field

FM radio

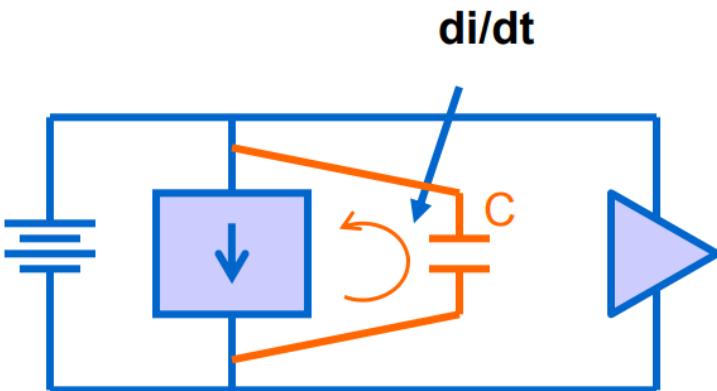
- Coupling via a common impedance
- E.g. via a common supply line or a ground connection

Circuit 1 : HF digital circuit

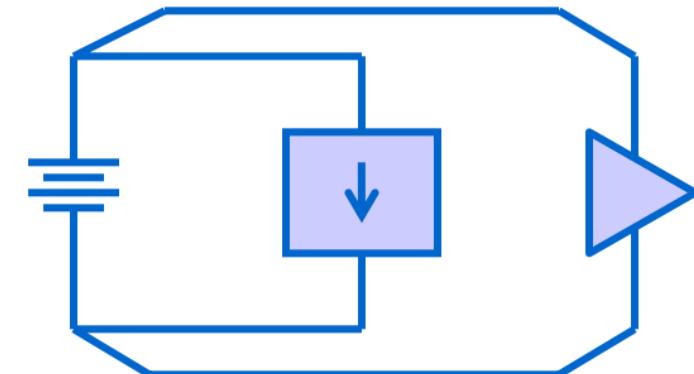
⇒ i_1 is a rapidly varying current (high di/dt)



- Quick fix: use a bypass capacitor near a HF circuit to locally deliver its rapidly changing supply currents (this can be seen as a form of filtering)
- Good design: avoid shared impedances



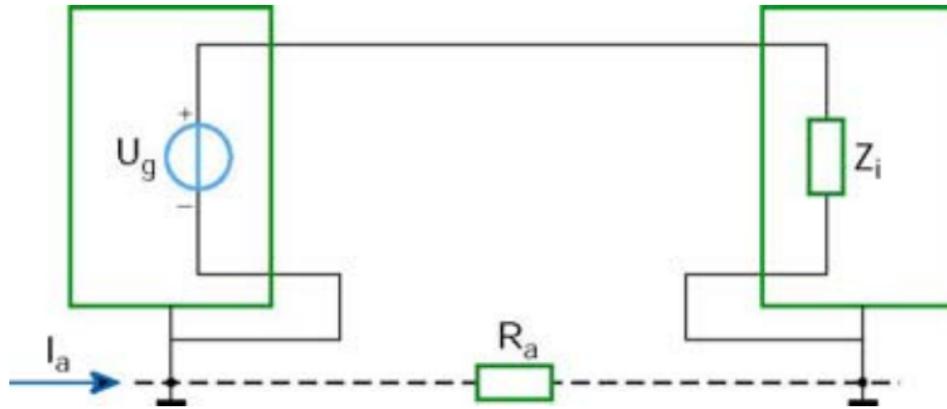
Local charge storage



Separate supply lines

Ground loops

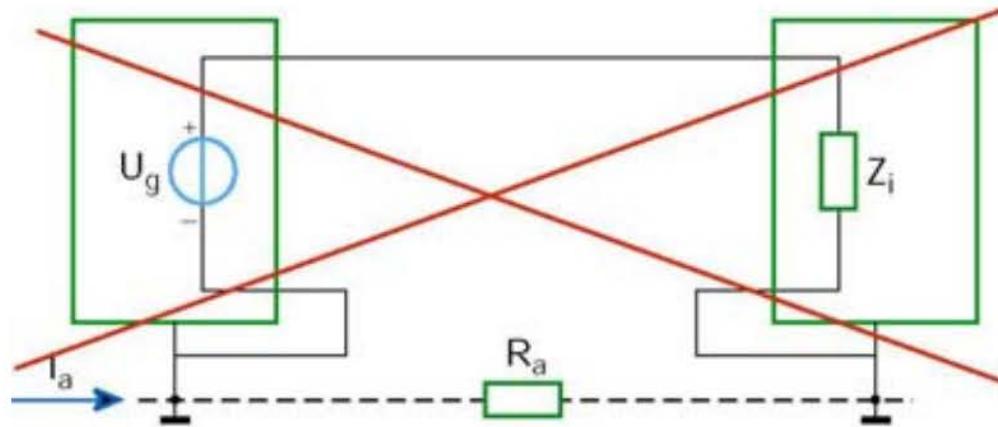
Additive error due to
 $I_a R_a$ in series with u_g .



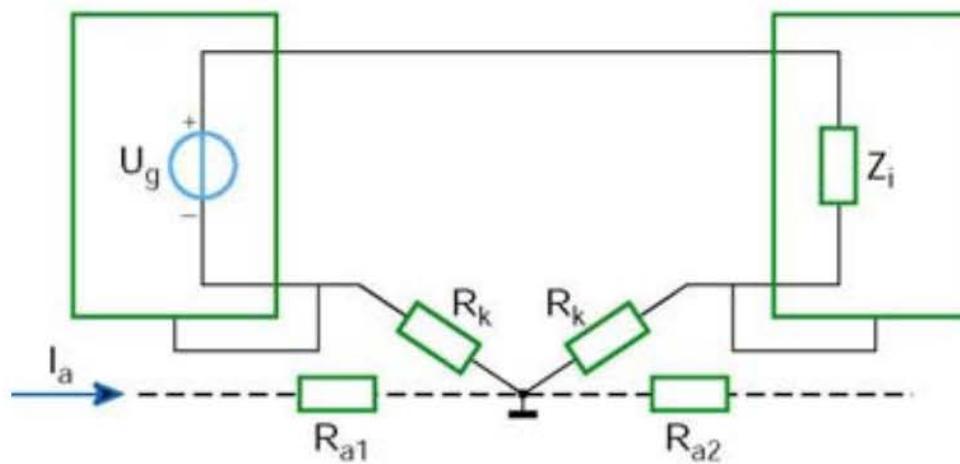
External sources of error

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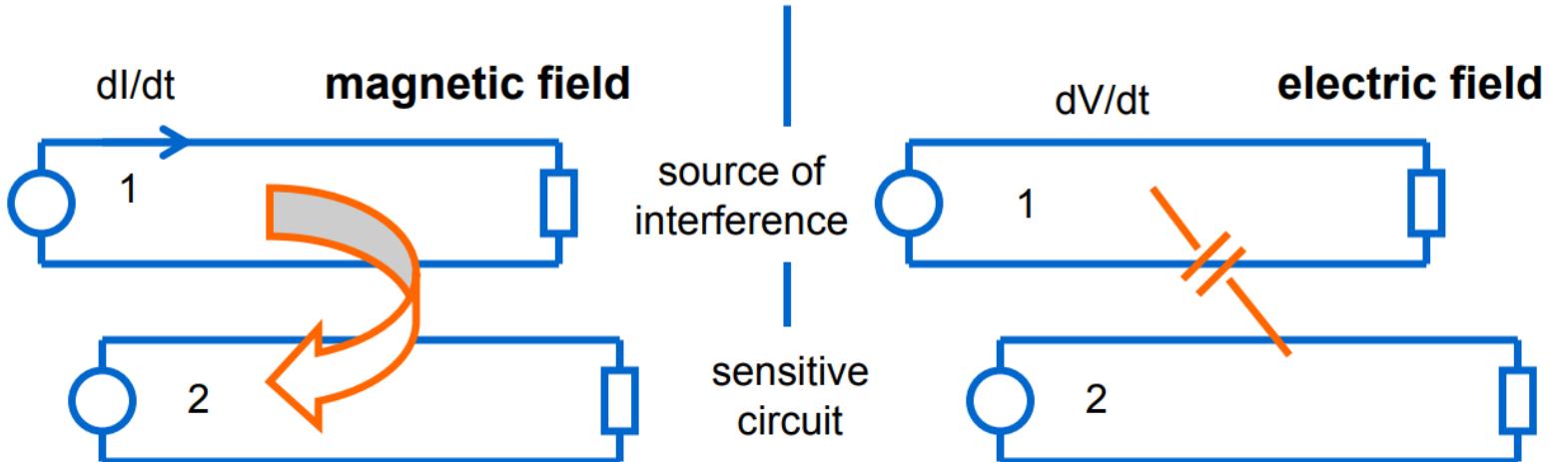
Ground loops



“star” connection to limit error due to $I_a R_a$.

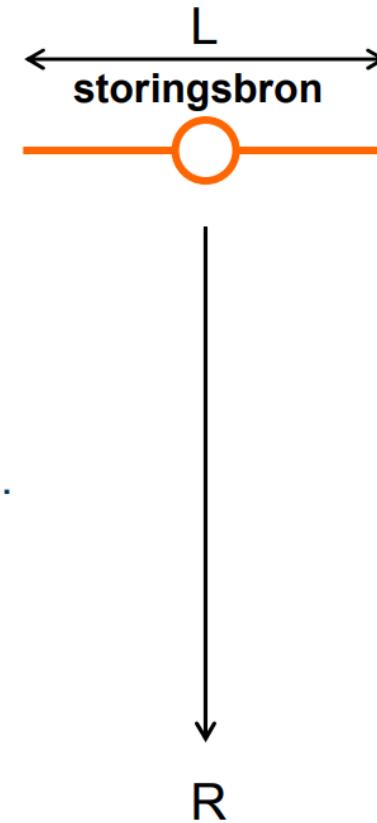


Electric (capacitive) coupling is due to changing voltages, i.e. dV/dt
Magnetic (inductive) coupling is due to changing currents, i.e. dI/dt



- **In the same circuit there can be multiple coupling mechanisms**
 - Depends on source and load-impedances, size and geometry

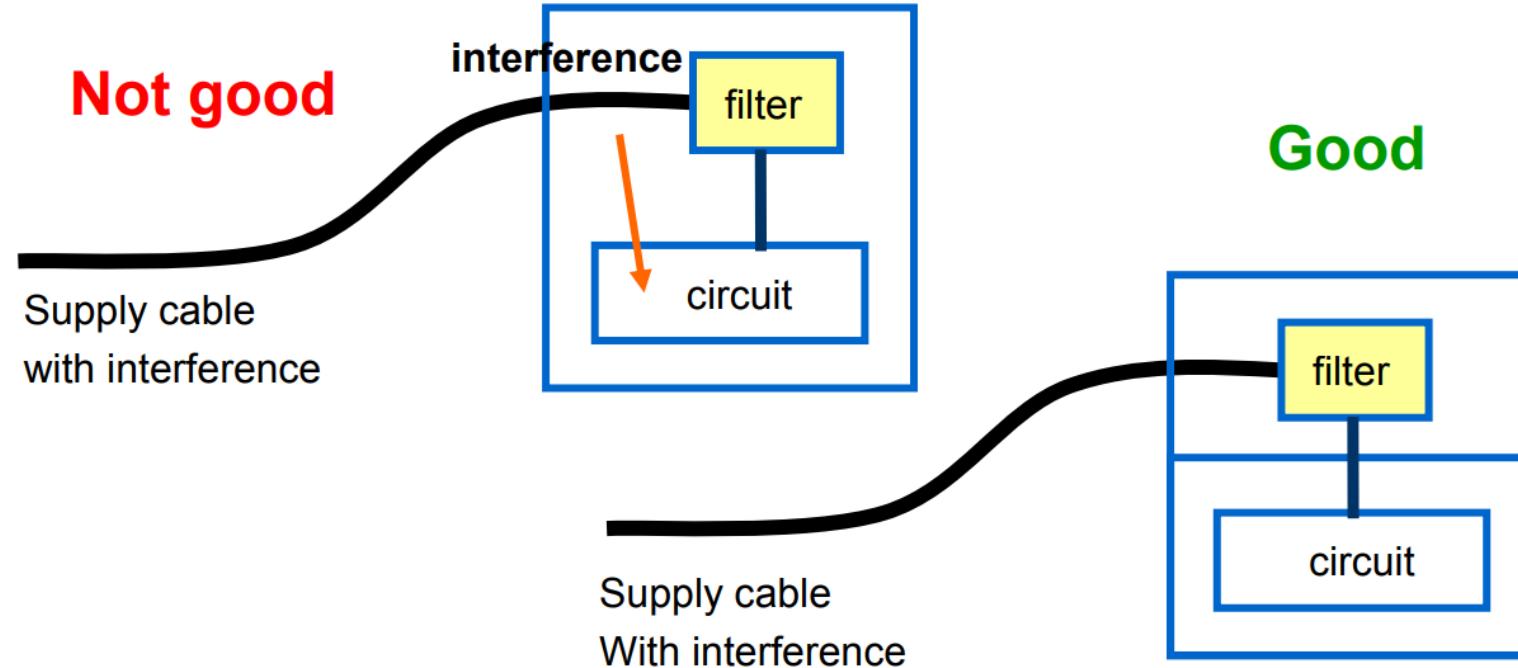
- When an “antenna” is driven by a source, it creates
 - an electromagnetic field
 - an electric field
 - a magnetic field
- In a given situation, the dominant field depends on the shape and size of the antenna, the frequency and the distance to the antenna
- Field strengths vary with:
 - $1/R^2$ and $1/R^3$ voor electric and magnetic fields, resp.
 $1/R$ for EM-waves (R = distance to antenna)
 - $R < \lambda$: E and M fields can dominate (near field)
 - $R > \lambda$: EM waves can dominate (far field)
- The following applies to EM waves:
 - $L = \lambda/2$: good antenna (lots of EM interference)
 - $L < \lambda/20$: bad antenna (less problems)



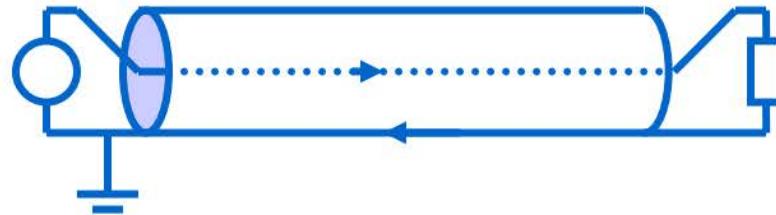
Interference reduction: Filtering

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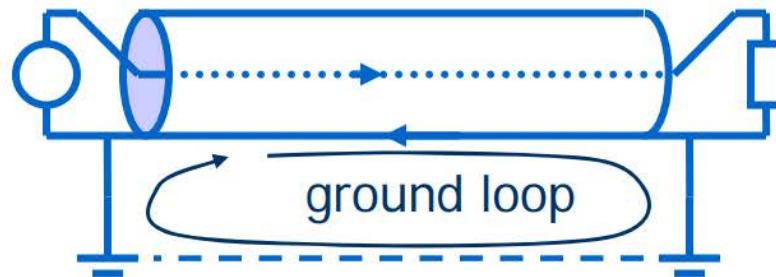
- Filtering can help suppress interference that is coupled into a circuit via its supply lines
- Filtering can also be used on signal lines if the interference does not occur at the same frequencies as the wanted signal



Shielding: Coax cable

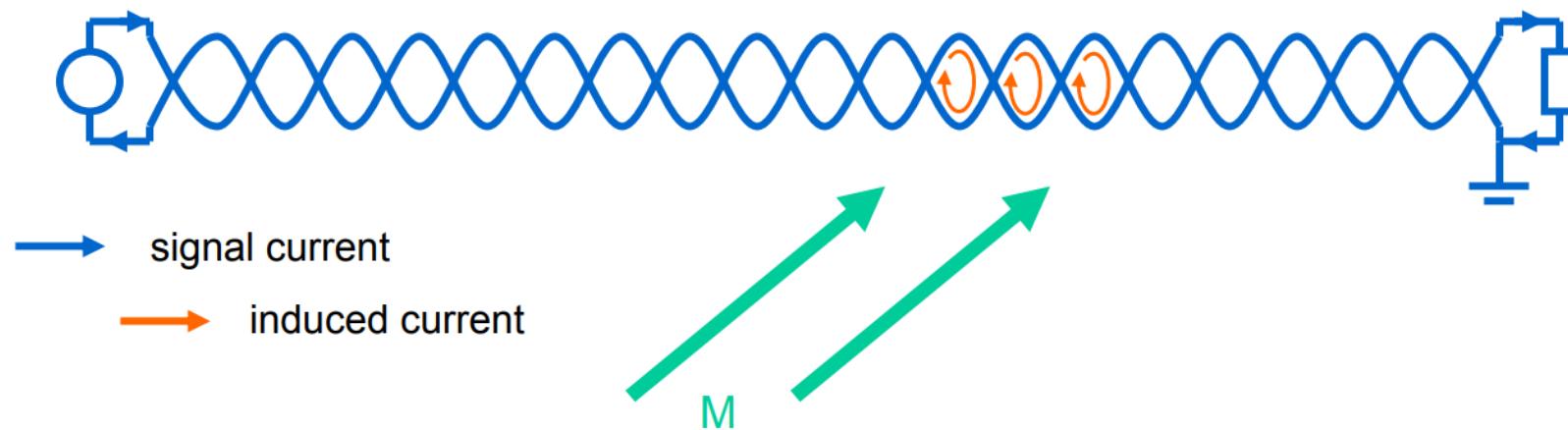


If the outer conductor of a coax cable (on 1 side) is grounded, electric field cannot reach the inner conductor. The outer conductor also forms the return path *and* the signal's reference.



If the outer is grounded at both sides (often the case) a ground loop will be created. This can lead to interference because of the voltage differences between the two grounds and/or magnetic coupling via the loop.

Twisted pair

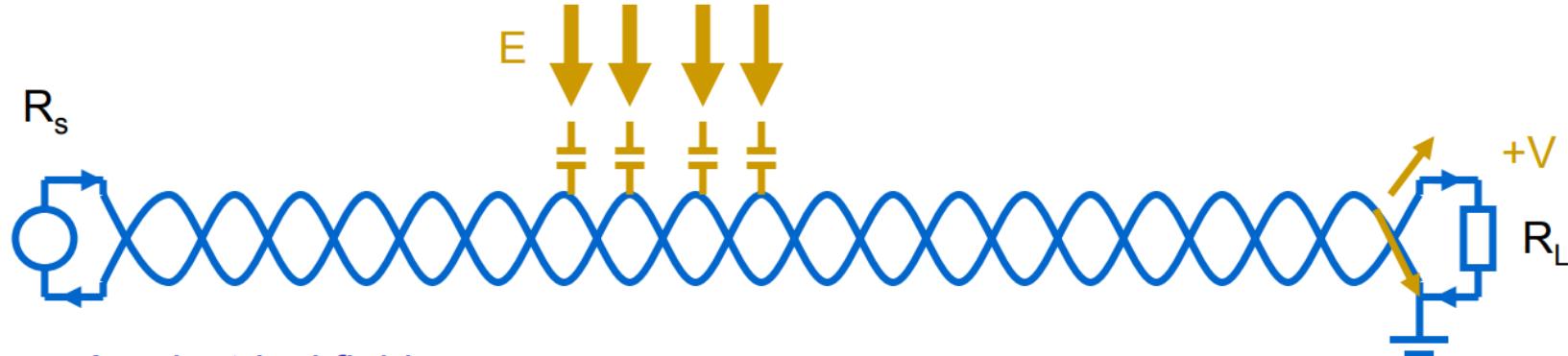


- Magnetic field induces current in coils
 - coils are “twisted”
 - currents in neighboring loops have opposite signs
 - currents cancel each other
 - *net induced current is zero*

	Attn [dB]
untwisted pair (ref)	0
twisted pair	43
untwisted pair + alu foil shield	3
untwisted pair + steel shield	32

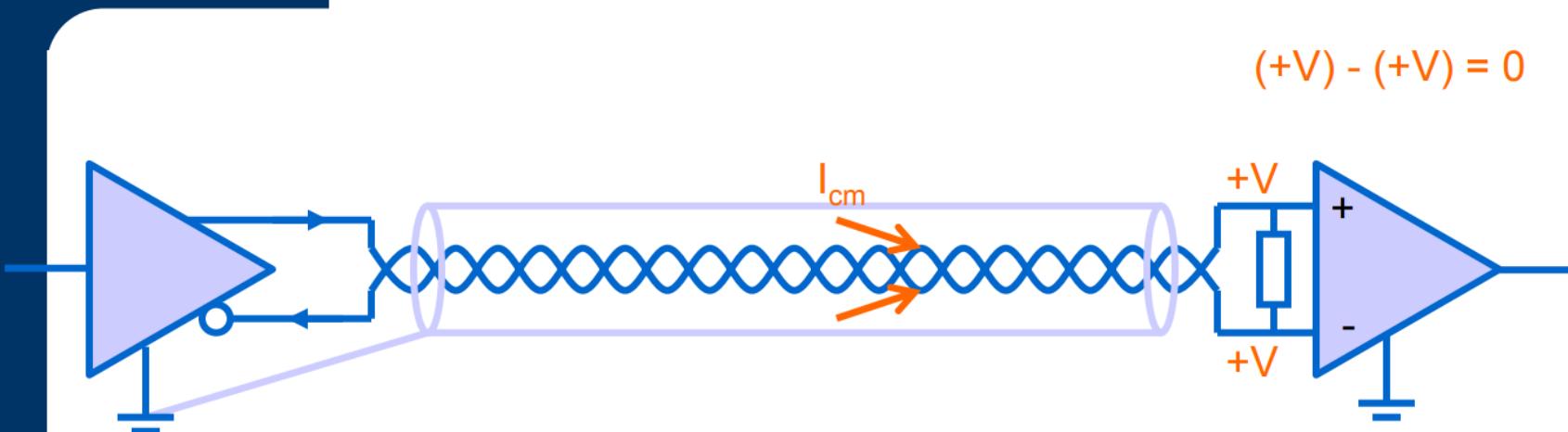
50 Hz **Magnetic** shielding

Twisted pair (2)



- An electrical field
 - Couples capacitively to both conductors
 - Generates equal currents in both signal and return lines
 - Signal line: current flows through $R_s//R_L$ generates $+V$
 - Return line: current flows to ground (low R)
- Result: electric fields are not shielded!
- Solutions:
 - Add capacitive shielding (e.g. a conducting outer layer)
 - Balance the circuit

Twisted pairs: Balancing

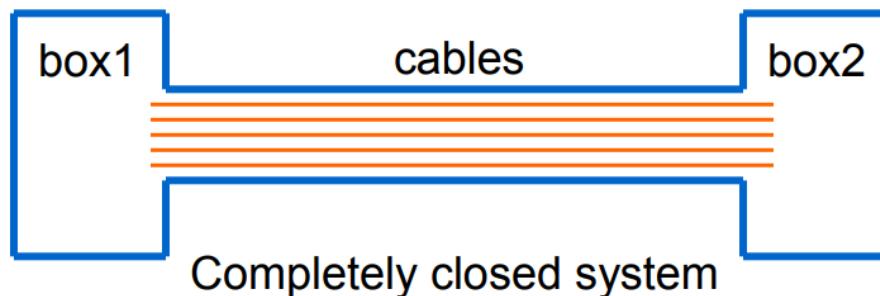
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Balancing:

- Use differential inputs and outputs
- Ensure that capacitively coupled currents in both lines are the same (i.e. that they are common-mode signals) and that they “see” the same impedance
- The current-induced voltages will then cancel each other out
- Adding an outer shield will then result in excellent suppression of both magnetic and electric interference

Shielding: EM waves

- EM waves will not penetrate a closed conducting enclosure if it is at least 10 “skin depths” thick
- The enclosure does not need to be grounded
- EM waves can leak into the enclosure via:
 - Cables that enter the enclosure
 - Use filters and/or shield the cables
 - Openings in the enclosure such as:
 - plastic knobs
 - displays
 - Ventilation holes
 - Poorly designed connectors



$$\delta = \frac{1}{\sqrt{\pi \cdot \sigma \cdot \mu \cdot f}}$$

δ = skin depth

σ = conductivity

μ = permeability

f = frequency

$1\delta = 8.7$ dB attn.
(= 2.7 x)

Types of cable

untwisted pair



coaxial



twin-axial



twisted-pair



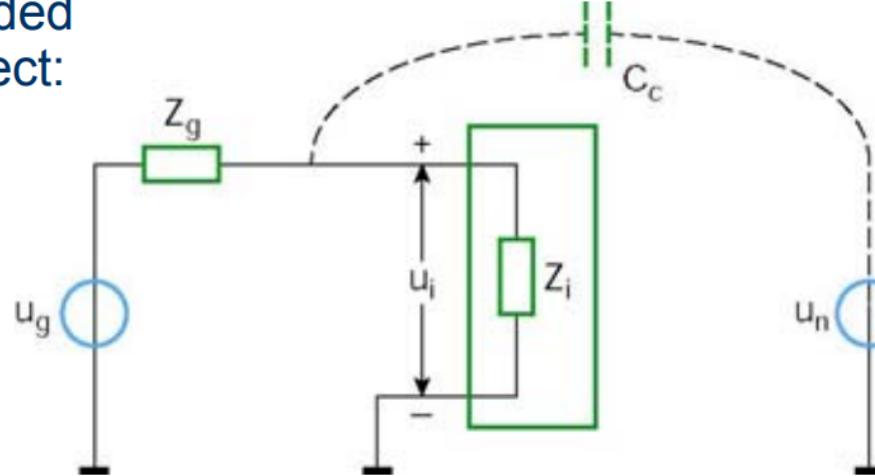
twisted-pair
shielded



**Most types of cable can be obtained with an extra outer shield
for even better suppression of EM interference**

Shielding to reduce capacitive coupling

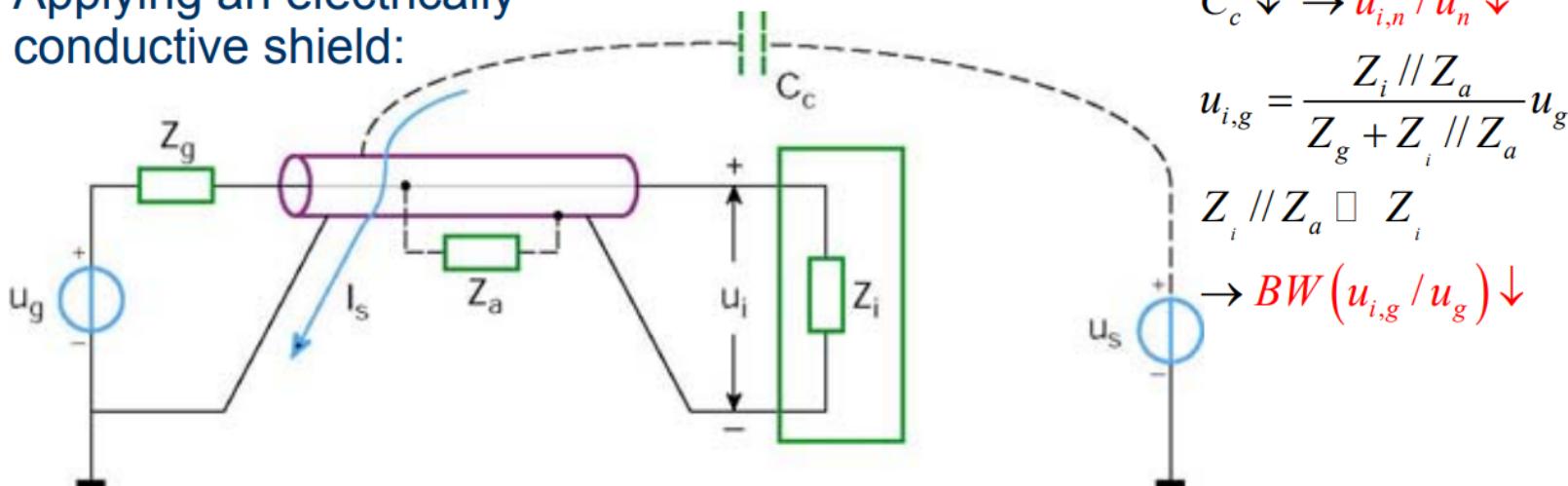
Non-shielded
interconnect:



$$u_{i,g} = \frac{Z_i}{Z_g + Z_i} u_g$$

$$u_{i,n} = \frac{Z_g // Z_i}{Z_g // Z_i + \frac{1}{j\omega C_c}} u_n$$

Applying an electrically
conductive shield:



$$C_c \downarrow \rightarrow u_{i,n} / u_n \downarrow$$

$$u_{i,g} = \frac{Z_i // Z_a}{Z_g + Z_i // Z_a} u_g$$

$$Z_i // Z_a \square Z_i$$

$$\rightarrow BW(u_{i,g} / u_g) \downarrow$$

Knowing how electric (capacitive) coupling arises, it is “easy” to avoid this type of interference:

- Reduce the signal impedances
 - The coupling cap and the signal impedance form a voltage divider
- Drop the frequency and amplitude of the interfering signal
 - Usually not possible
- Decrease the coupling capacitance
 - Increase the distance between interference and circuit
 - Ground floating conductors between interference and circuit
- Break any return path for interference
 - These usually form ground loops
- Capacitive shielding:
 - Shielded cables (e.g. coax)
 - Conducting box around sensitive circuits
 - Ground the shielding!